Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (Ultra-High-Speed U-MOSⅢ)

TK50X15J1

DC-DC Converters

Low drain-source ON-resistance: R_{DS} (ON) = 22 mΩ (typ.)

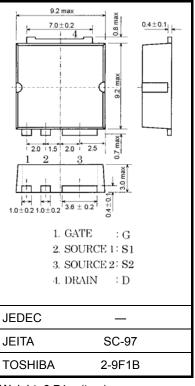
• High forward transfer admittance: $|Y_{fs}| = 90 \text{ S (typ.)}$

• Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 150 \text{ V)}$

• Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	150	V	
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	150	V	
Gate-source voltage		V _{GSS}	±20	V	
Drain current	DC (Note 1)	ID	50	Α	
	Pulse (Note 1)	I _{DP}	150	A	
Drain power dissipation	on (Tc = 25°C)	P _D	125	W	
Single pulse avalanche energy (Note 2)		E _{AS}	182	mJ	
Avalanche current		I _{AR}	50	Α	
Repetitive avalanche	energy (Note 3)	E _{AR}	10.9	mJ	
Channel temperature	(Note 4)	T _{ch}	175	°C	
Storage temperature	range (Note 4)	T _{stg}	-55 to 175	°C	



Weight: 0.74 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit	
Thermal resistance, channel to case	R _{th (ch-c)}	1.2	°C/W	

Note 1: Ensure that the channel temperature does not exceed 175°C.

Note 2: $V_{DD} = 50V$, $T_{ch} = 25$ °C (initial), $L = 110 \mu H$, $R_G = 25 \Omega$, $I_{AR} = 50A$

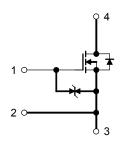
Note 3: Repetitive rating: pulse width limited by maximum channel temperature

Note 4: The definitions of the absolute maximum channel and storage temperatures are base on AEC-Q101.

This transistor is an electrostatic-sensitive device. Handle with care.

Circuit Configuration

Note: Use the S1 pin to return the gate signal to source. Board traces should be designed so the main current flows to the S2 pin.



Electrical Characteristics (Note 5) (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	Gate leakage current I_{GSS} $V_{GS} = \pm 16 \text{ V}, \text{ V}$		$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Drain cut-OFF cu	rrent	I _{DSS}	V _{DS} = 150 V, V _{GS} = 0 V	_	_	10	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	150		_	V
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	95	—	_	
Gate threshold voltage		V _{th}	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$	2.0	—	4.0	V
Drain-source ON-resistance		R _{DS} (ON)	$V_{GS} = 10 \text{ V}, I_D = 25 \text{ A}$		22	30	mΩ
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 25 A	45	90	_	S
Input capacitance		C _{iss}			4300	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		210	_	
Output capacitance		Coss			640	_	
Switching time	Rise time	t _r	$V_{GS} = 25 \text{ A} \\ V_{GS} = 25 \text{ A} \\ V_{OUT} = 3 \Omega$ $V_{DD} \approx 75 \text{ V}$ $V_{DD} \approx 75 \text{ V}$	_	7	_	ns
	Turn-ON time	t _{on}		_	30	_	
	Fall time	t _f			15	_	
	Turn-OFF time	t _{off}		_	85	_	
Total gate charge (gate-source plus gate-drain)		Qg			75	_	nC
Gate-source charge1		Q _{gs1}	$V_{DD} \approx 120 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 50 \text{ A}$	_	25	_	
Gate-drain ("miller") charge		Q _{gd}			25	_	
Gate switch charge		Q _{sw}			33		

Note 5: The S1 and S2 pins should be grounded together, except when measuring the switching time.

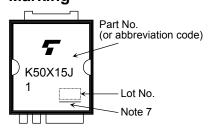
Source-Drain Ratings and Characteristics (Note 6) (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1, Note 6)	I _{DR} 1	_	_	_	50	Α
Pulse drain reverse current (Note 1,Note 6)	I _{DRP} 1	_	_		150	Α
Continuous drain reverse current (Note 1, Note 6)	I _{DR} 2	_	_		1	Α
Pulse drain reverse current (Note 1,Note 6)	I _{DRP} 2	_	_	_	4	Α
Forward voltage (diode)	V _{DS2F}	I _{DR} 1 = 50 A, V _{GS} = 0 V	_		-1.5	V
Reverse recovery time	t _{rr}	$I_{DR} = 50 \text{ A}, V_{GS} = 0 \text{ V},$		95		ns
Reverse recovery charge	Q _{rr}	dl _{DR} /dt = 100 A/μs	_	450	_	nC

Note 6: I_{DR}1, I_{DRP}1: Current flowing between the drain and S2 pins. Ensure that the S1 pin is left open. I_{DR}2, I_{DRP}2: Current flowing between the drain and S1 pins. Ensure that the S2 pin is left open. The S1 and S2 pins should be grounded together, unless otherwise noted.

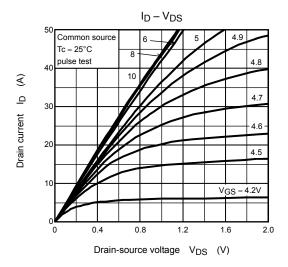
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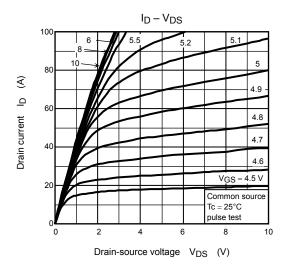
Marking

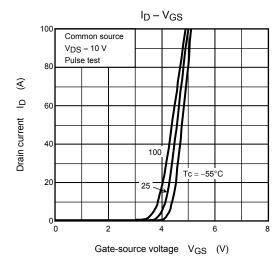


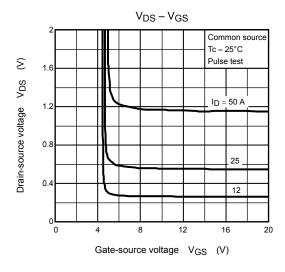
Note 7: A line under a Lot No. identifies the indication of product Labels. [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

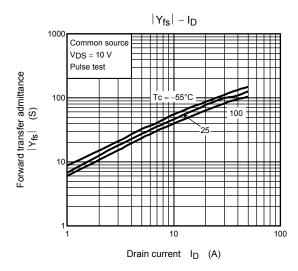
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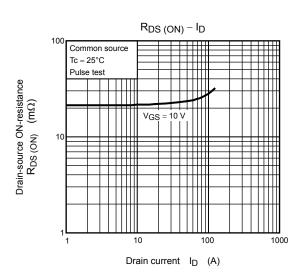


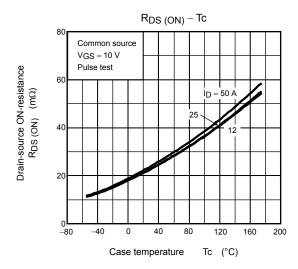


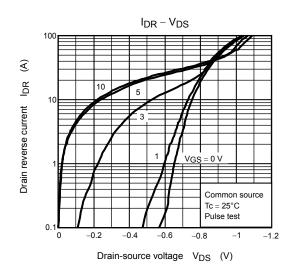


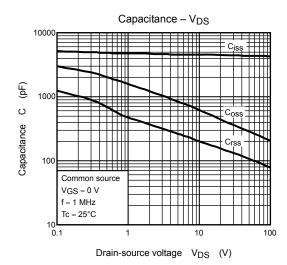


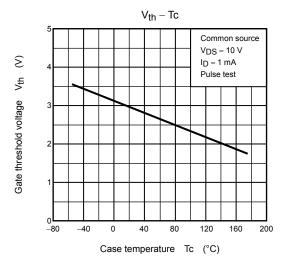


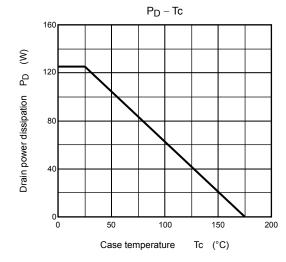


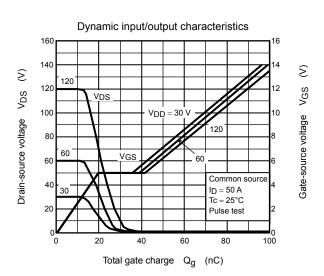


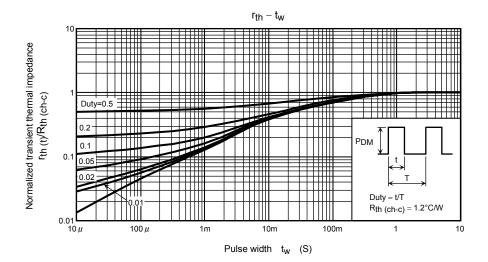


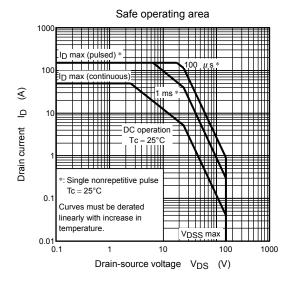


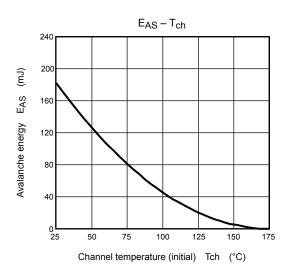


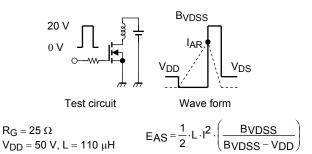












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